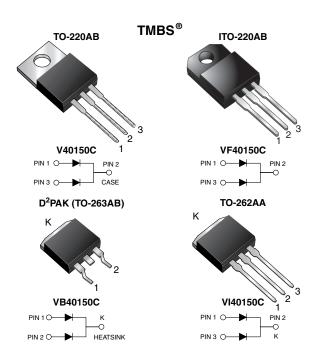
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# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.55 \text{ V}$  at  $I_F = 5 \text{ A}$ 



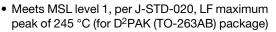
### **LINKS TO ADDITIONAL RESOURCES**

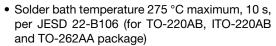


PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 20 A					
V <sub>RRM</sub>	150 V					
I <sub>FSM</sub> 160 A						
$V_F$ at $I_F = 20 A$	0.75 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation





 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

### **MECHANICAL DATA**

**Case:** TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V40150C	VF40150C	VB40150C	VI40150C	UNIT	
Max. repetitive peak reverse voltage			150					
Max. average forward rectified current	per device	I <sub>F(AV)</sub>	40			Α		
(fig. 1)	per diode	I <sub>F(AV)</sub>	20					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	160			Α		
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 60 mH per diode			150			mJ		
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C per diode			0.5			Α		
Voltage rate of change (rated V <sub>R</sub> )			10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			1500			V		
Operating junction and storage temperature range			-55 to +150			°C		

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP	MAX.	UNIT		
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	$V_{BR}$	150 (min.)	-	V		
Instantaneous forward voltage per diode (1)	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub>	0.69	-	V		
	I <sub>F</sub> = 10 A			0.84	-			
	I <sub>F</sub> = 20 A			1.15	1.43			
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.55	-			
	I <sub>F</sub> = 10 A			0.64	-			
	I <sub>F</sub> = 20 A			0.75	0.82			
Reverse current per diode (2)	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	2	-	μΑ		
		T <sub>A</sub> = 125 °C		2.5	-	mA		
	V <sub>R</sub> = 150 V	T <sub>A</sub> = 25 °C		-	250	μΑ		
		T <sub>A</sub> = 125 °C		5	25	mA		

### **Notes**

<sup>(2)</sup> Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V40150C	VF40150C	VB40150C	VI40150C	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	1.8	4	1.8	1.8	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V40150C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VF40150C-E3/4W	1.75	4W	50/tube	Tube			
D <sup>2</sup> PAK (TO-263AB)	VB40150C-E3/4W	1.39	4W	50/tube	Tube			
D <sup>2</sup> PAK (TO-263AB)	VB40150C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI40150C-E3/4W	1.46	4W	50/tube	Tube			

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

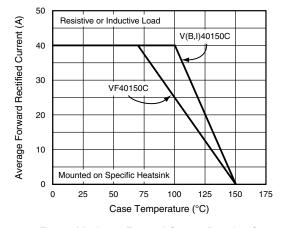


Fig. 1 - Maximum Forward Current Derating Curve

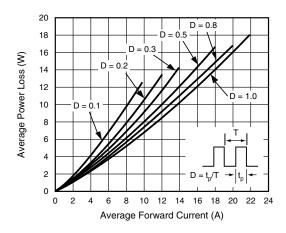


Fig. 2 - Forward Power Loss Characteristics Per Diode

 $<sup>^{(1)}\,</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

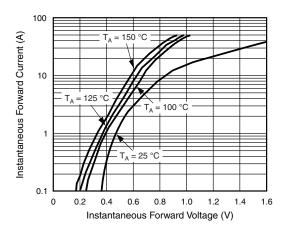


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

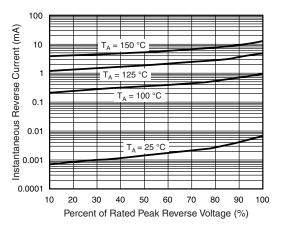


Fig. 4 - Typical Reverse Characteristics Per Diode

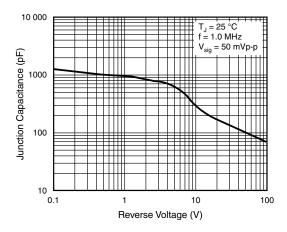


Fig. 5 - Typical Junction Capacitance

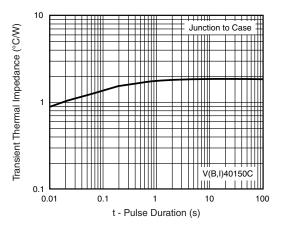


Fig. 6 - Typical Transient Thermal Impedance Per Diode

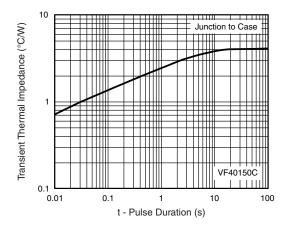
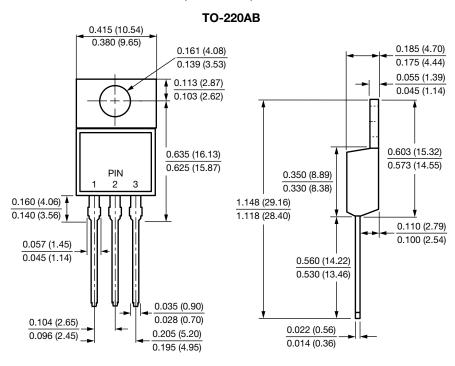


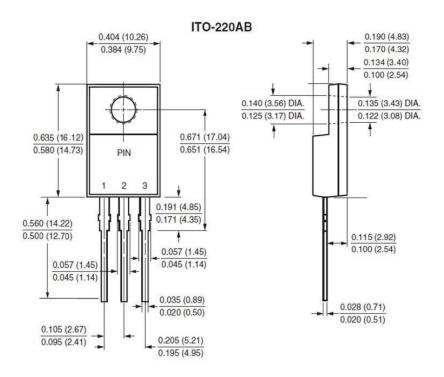
Fig. 7 - Typical Transient Thermal Impedance Per Diode

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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

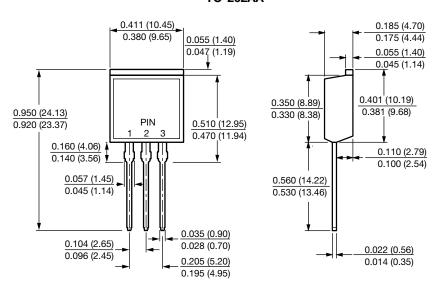




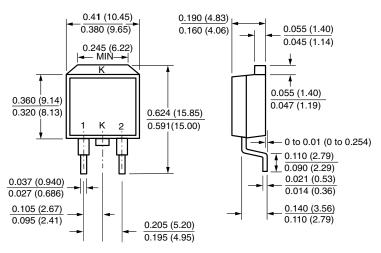
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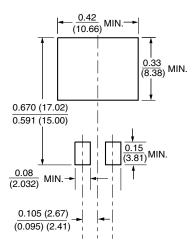
### TO-262AA



### D<sup>2</sup>PAK (TO-263AB)



### **Mounting Pad Layout**





## **Legal Disclaimer Notice**

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